

IPD200N15N3GATMA1

Data Sheet

MOSFET TRENCH >= 100V

Manufacturers <u>Infineon Technologies Corporation</u>

Package/Case TO-252-3

Product Type Transistors

RoHS

Lifecycle



Images are for reference only

Please submit RFQ for IPD200N15N3GATMA1 or Email to us: sales@ovaga.com We will contact you in 12 hours.

RFO

General Description

The 150V OptiMOSTM achieves a reduction in R DS(on) of 40% and of 45% in figure of merit (FOM) compared to the next best competitor. This drastic improvement opens new possibilities like moving from leaded packages to SMD packages or effectively replacing two old parts with one OptiMOSTM part.

Features

Excellent switching performance

World's lowest R DS(on)

Very low Q g and Q gd

Excellent gate charge x R DS(on) product (FOM)

RoHS compliant-halogen free

MSL1 rated 2

Environmentally friendly

Increased efficiency

Highest power density

Less paralleling required

Smallest board-space consumption

Easy-to-design products

Application

Synchronous rectification for AC-DC SMPS

Isolated DC-DC converters (telecom and datacom systems)

Or-ing switches and circuit breakers in 48V systems

Class D audio amplifiers



Related Products



IPP60R070CFD7

Infineon Technologies Corporation TO-220-3



IPB180N06S4-H1

Infineon Technologies Corporation PG-TO263-7-3



IPG20N04S4-12

Infineon Technologies Corporation TDSON-8



IPD25N06S4L-30

Infineon Technologies Corporation PG-TO252-3



IPP60R074C6

Infineon Technologies Corporation TO-220-3



IPW65R080CFD

Infineon Technologies Corporation TO-247



IPD180N10N3G

Infineon Technologies Corporation TO-252



IPD70R1K4P7S

Infineon Technologies Corporation TO252-3